



M1-M7

Features:

- ☐ For surface mounted applications
- ☐ Low profile package
- ☐ Glass Passivated Chip Junction
- ☐ Easy to pick and place
- ☐ Lead free in comply with EU RoHS 2011/65/EU directives

DO-214AC
(SMA)

1. Cathode 2. Anode

Absolute Maximum Ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Parameter	Symbols	M1	M2	M3	M4	M5	M6	M7	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}	30							A
Maximum Instantaneous Forward Voltage at 1 A	V_F	1.1							V
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 125^\circ\text{C}$	I_R	5 50							μA
Typical Junction Capacitance ⁽¹⁾	C_j	15							pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	75							$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{stg}	$-55 \sim +150$							$^\circ\text{C}$

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 1.0 X 1.0" (2.54 X 2.54 cm) copper pad areas.

Typical Characteristics

Fig.1 Forward Current Derating Curve

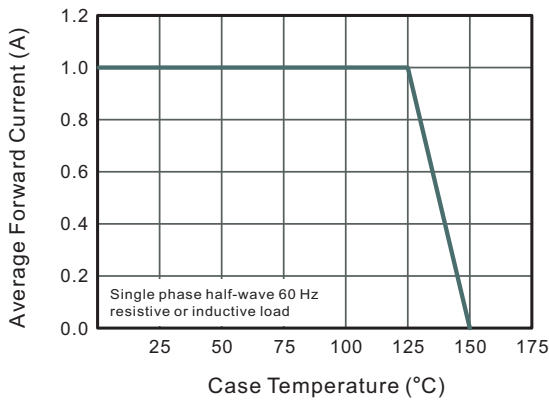


Fig.2 Typical Instantaneous Reverse Characteristics

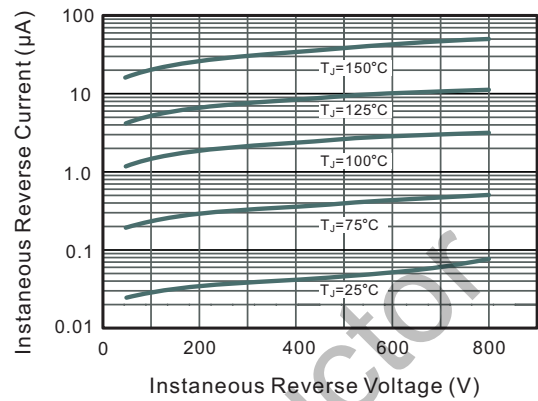


Fig.3 Typical Forward Characteristic

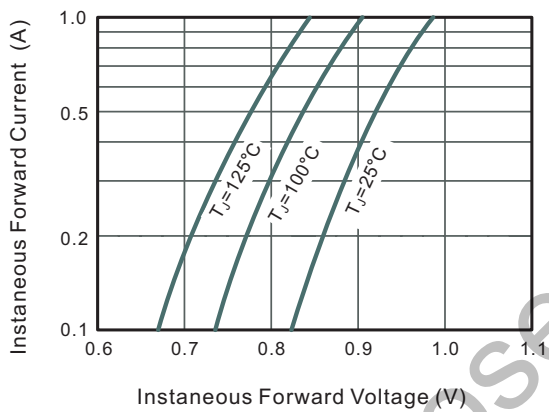


Fig.4 Typical Junction Capacitance

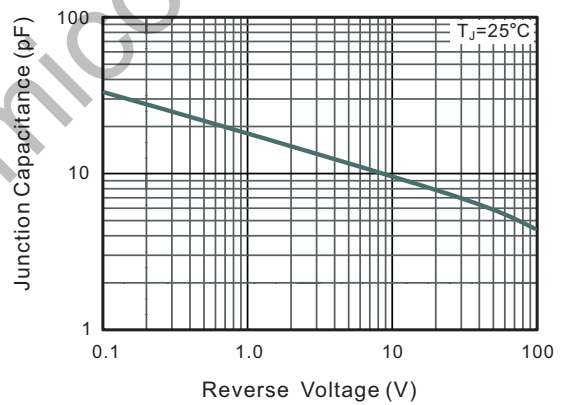
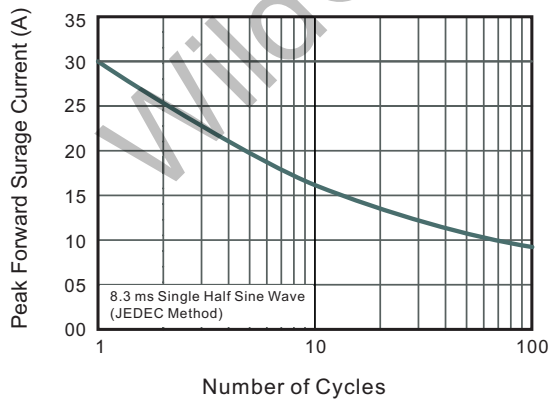


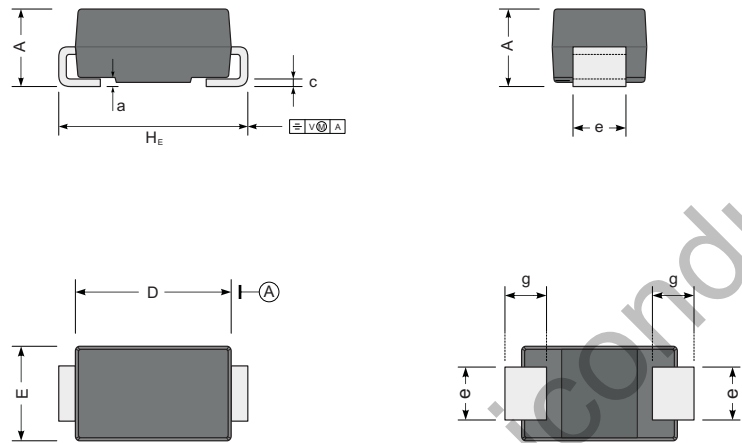
Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



Package Dimension

SMA

Unit: mm



UNIT		A	D	E	H _E	c	e	g	a
mm	max	2.2	4.5	2.7	5.2	0.31	1.6	1.5	0.3
	min	1.9	4.0	2.3	4.7	0.15	1.3	0.9	
mil	max	87	181	106	205	12	63	59	12
	min	75	157	91	185	6	51	35	

The recommended mounting pad size

